

RoHS

COMPLIANT

HALOGEN FREE

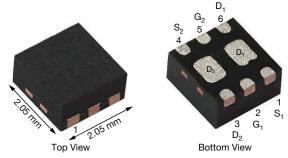


www.vishay.com

# **Dual P-Channel 20 V (D-S) MOSFET**

PRODUCT SUMMARY									
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)	Q <sub>g</sub> (TYP.)						
-20	0.057 at V <sub>GS</sub> = -4.5 V	-4.5 <sup>a</sup>	4.9 nC						
	0.095 at V <sub>GS</sub> = -2.5 V	-4.5 <sup>a</sup>	4.9110						

### PowerPAK® SC-70-6L Dual



Marking Code: DM Ordering Information:

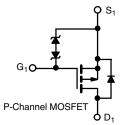
<u>SiA907EDJT-T1-GE3</u> (Lead (Pb)-free and Halogen-free) <u>SiA907EDJT-T4-GE3</u> (Lead (Pb)-free and Halogen-free)

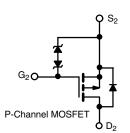
#### **FEATURES**

- TrenchFET® power MOSFET
- Thermally enhanced Thin PowerPAK® SC-70 package
  - Small footprint area
  - Low on-resistance
- Typical ESD protection: 1500 V HBM
- · High speed switching
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- Charger Switch, Load Switch for Portable Devices
- Battery Management





<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)								
PARAMETER		SYMBOL	LIMIT	UNIT				
Drain-Source Voltage		V <sub>DS</sub>	-20	V				
Gate-Source Voltage		V <sub>GS</sub>	± 12	v				
	T <sub>C</sub> = 25 °C		-4.5 <sup>a</sup>					
Continuous Drain Current /T 150 °C)	T <sub>C</sub> = 70 °C		-4.5 <sup>a</sup>					
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	-4.5 a, b, c					
	T <sub>A</sub> = 70 °C		-3.8 b, c	Α				
Pulsed Drain Current (t = 300 μs)		I <sub>DM</sub>	-15					
Castinua Causa Durin Diada Cumant	T <sub>C</sub> = 25 °C	,	-4.5 <sup>a</sup>					
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	-1.6 <sup>b, c</sup>					
	T <sub>C</sub> = 25 °C		7.8					
Mayimum Dawar Dissination	T <sub>C</sub> = 70 °C		5	w				
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.9 <sup>b, c</sup>	VV				
	T <sub>A</sub> = 70 °C		1.2 <sup>b, c</sup>	7				
Operating Junction and Storage Temperature Ra	nge	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C				
Soldering Recommendations (Peak Temperature)	) d, e		260	7				

THERMAL RESISTANCE RATINGS									
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT				
Maximum Junction-to-Ambient b, f	t ≤ 5 s	R <sub>thJA</sub>	52	65	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	12.5	16	C/VV				

### Notes

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. See solder profile (www.vishay.com/doc?73257). The Thin PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: Manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under steady state conditions is 110 °C/W.

# Vishay Siliconix

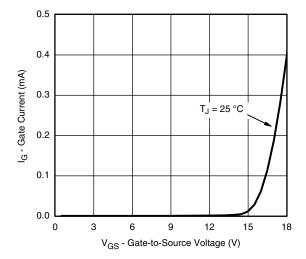
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20	-	-	V		
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I - 250 uA	-	-14	-	mV/°C		
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = -250 μA	-	2.5	-			
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-0.5	-	-1.4	V		
Cata Sauraa Laakaga	1	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$	-	-	± 0.5			
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$	-	-	± 10	μΑ		
Zava Cata Valtaga Dvain Cuwant	1	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$	-	-	-10			
On-State Drain Current <sup>a</sup>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-15	-	-	Α			
Drain Course On State Besisters 2	D <sub>n</sub> c: :	$V_{GS} = -4.5 \text{ V}, I_D = -3.6 \text{ A}$	-	0.047	0.057	Ω		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -1.5 \text{ A}$	-	0.075	0.095			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	11 (01/1 0.01		11	-	S		
Dynamic <sup>b</sup>								
Total Cata Charge	Qg	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -4.7 \text{ A}$	-	15	23	nC		
Total Gate Charge			=	7.1	11			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -4.7 \text{ A}$	-	1.3	-			
Gate-Drain Charge	$Q_{gd}$		-	2.1	-			
Gate Resistance	$R_g$	f = 1 MHz	1.4	7	14	Ω		
Turn-On Delay Time	t <sub>d(on)</sub>		-	13	25			
Rise Time	t <sub>r</sub>	$V_{DD}$ = -10 V, $R_L$ = 2.7 $\Omega$	-	15	30	ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ -3.7 A, $V_{GEN}=$ -4.5 V, $R_g=$ 1 $\Omega$	-	30	60			
Fall Time	t <sub>f</sub>		-	10	15			
Turn-On Delay Time	t <sub>d(on)</sub>		-	5	10			
Rise Time	t <sub>r</sub>	$V_{DD}$ = -10 V, $R_L$ = 2.7 $\Omega$	-	10	20			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ -3.7 A, $V_{GEN}=$ -10 V, $R_g=$ 1 $\Omega$	-	30	60			
Fall Time	t <sub>f</sub>		-	10	20			
<b>Drain-Source Body Diode Characterist</b>	ics							
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	-	-	-4.5	Α		
Pulse Diode Forward Current	I <sub>SM</sub>		-	-	-15	^		
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = -3.7 A, V <sub>GS</sub> = 0 V	-	-0.9	-1.2	V		
Body Diode Reverse Recovery Time	t <sub>rr</sub>		-	15	30	ns		
Body Diode Reverse Recovery Charge	$Q_{rr}$	L_ 27 A dl/dt = 100 A/va T = 05 °C	-	6	12	nC		
Reverse Recovery Fall Time	t <sub>a</sub>	$I_F = -3.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$	-	8.5	-	ns		
Reverse Recovery Rise Time	t <sub>b</sub>		-	6.5	-			

#### **Notes**

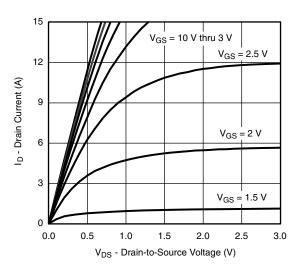
- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

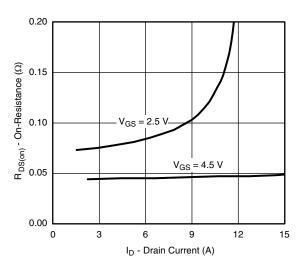




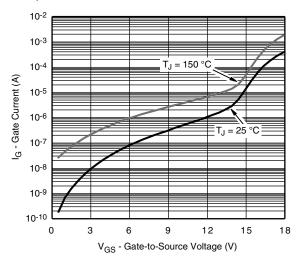
Gate Current vs. Gate-to-Source Voltage



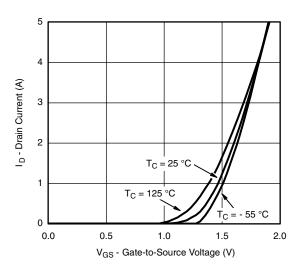
**Output Characteristics** 



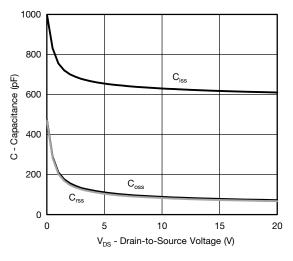
On-Resistance vs. Drain Current and Gate Voltage



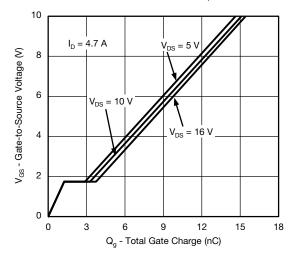
Gate Current vs. Gate-to-Source Voltage



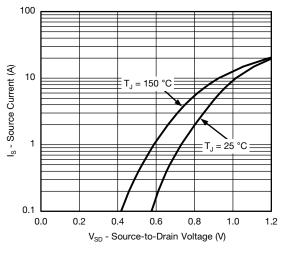
**Transfer Characteristics** 



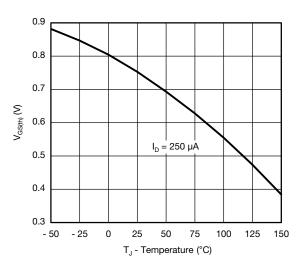




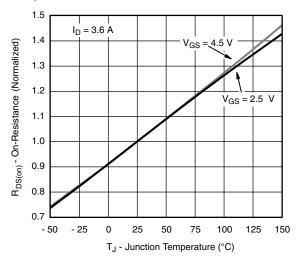
### **Gate Charge**



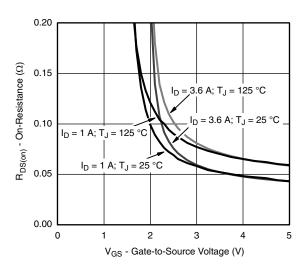
## Source-Drain Diode Forward Voltage



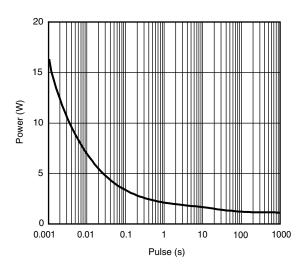
**Threshold Voltage** 



On-Resistance vs. Junction Temperature

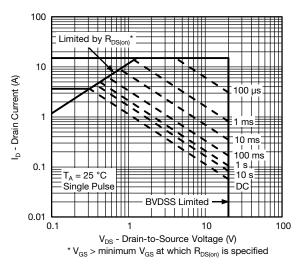


On-Resistance vs. Gate-to-Source Voltage

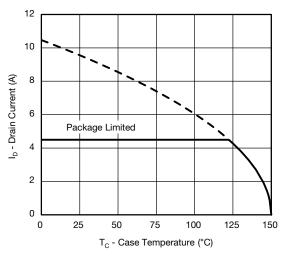


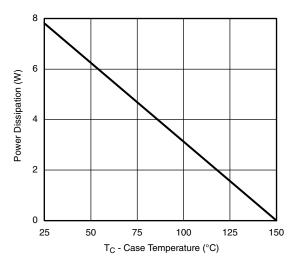
Single Pulse Power, Junction-to-Ambient





Safe Operating Area, Junction-to-Ambient



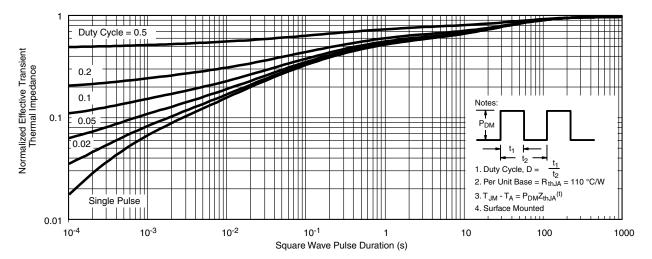


**Power Derating** 

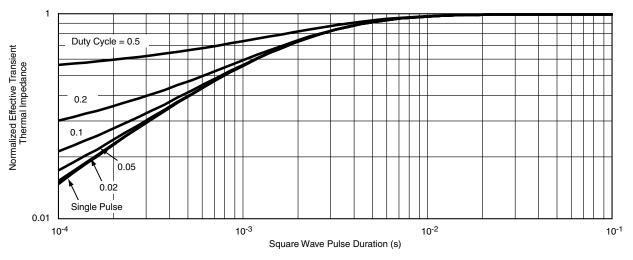
**Current Derating\*** 

<sup>\*</sup> The power dissipation  $P_D$  is based on  $T_J$  (max.) = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





### Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

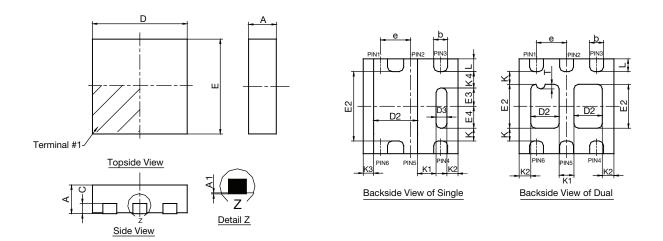
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# Case Outline for PowerPAK® SC70T



			SING	LE PAD			DUAL PAD					
DIM.	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.525	0.60	0.65	0.0206	0.024	0.026	0.525	0.60	0.65	0.0206	0.024	0.026
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D2	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D3	0.135	0.235	0.335	0.005	0.009	0.013						
Ε	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E2	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E3	0.345	0.395	0.445	0.014	0.016	0.018						
E4	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC 0.026 BSC				0.65 BSC 0.026 BSC						
K	0.275 TYP.				0.011 TYP		0.275 TYP. 0.011 TYP.					
K1	0.400 TYP.			0.016 TYP.			0.320 TYP.		0.013 TYP.			
K2	0.240 TYP.			0.009 TYP.		0.252 TYP.		0.010 TYP.				
K3	0.225 TYP.				0.009 TYP							
K4	0.355 TYP.				0.014 TYP							
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
•	<u> </u>  2-0160-Re	v. B. 05-Ma	ı ar-12	[			0.05	0.10	0.15	0.002	0.004	0.000

ECN: C12-0160-Rev. B, 05-Mar-12

## DWG: 5994

**Notes** 

- 1. All dimensions are in millimeter. Millimeters will govern.
- 2. Package outline exculsive of mold flash and metal burr.
- 3. Package outline inclusive of plating



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Vishay

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Revision: 13-Jun-16 1 Document Number: 91000

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